NSN 5962-01-387-6475

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.2 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and monolithic and programmed and electrostatic sensitive
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Case Outline Source And Designator:
D-9 mil-m-38510
Current Rating Per Characteristic:
100.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Capitance Rating Per Characteristic:
10.00 input picofarads and 10.00 output picofarads
Time Rating Per Chacteristic:
10.00 nanoseconds access
Memory Device Type:
Pal
Test Data Document:
$96906 \hbox{-mil-std-}883 \ standard \ (includes \ industry \ or \ association \ standards, \ individual \ manufactureer \ standards, \ etc.).$
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
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